## NSN 5961-01-324-5887

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-324-5887

Metal

**Overall Length:** 

1.580 inches

## **Overall Height:**

0.450 inches

#### **Overall Width:**

1.050 inches

#### **Function For Which Designed:**

Switching

#### **End Application:**

5805-01-188-3993 central office, telephone, automatic

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

## Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

## **Features Provided:**

Hermetically sealed case and burn in and electrostatic sensitive

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

50.00 amperes source cutoff current and 10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

170.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

# NSN 5961-01-324-5887

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

